

The RF Line

PNP Silicon

High-Frequency Transistor

Designed primarily for use in the high-gain, low-noise small-signal amplifiers for operation up to 3.5 GHz. Also usable in applications requiring fast switching times.

- High Current Gain-Bandwidth Product —
 $f_T = 3.4 \text{ GHz (Typ) @ } I_C = -35 \text{ mAdc (MMBR521LT1)}$
 $f_T = 4.2 \text{ GHz (Typ) @ } I_C = -50 \text{ mAdc (MRF5211LT1)}$
- Low Noise Figure @ $f = 1.0 \text{ GHz}$ —
 $NF(\text{matched}) = 2.5 \text{ dB (Typ) (MMBR521LT1)}$
 $NF(\text{matched}) = 2.8 \text{ dB (Typ) (MRF5211LT1)}$
- High Power Gain — $G_{pe}(\text{matched}) = 11 \text{ dB (Typ)}$
- Guaranteed RF Parameters
- Surface Mounted SOT-23 (MMBR521LT1) & SOT-143 (MRF5211LT1)
 Offer Improved RF Performance
 Lower Package Parasitics
 Higher Gain
- Available in tape and reel packaging options:
 T1 suffix = 3,000 units per reel

MAXIMUM RATINGS

Ratings	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	-10	Vdc
Collector-Base Voltage	V_{CBO}	-20	Vdc
Emitter-Base Voltage	V_{EBO}	-2.5	Vdc
Power Dissipation (1) $T_C = 75^\circ\text{C}$, Derate linearly above $T_C = 75^\circ\text{C}$ @ All	$P_{D(\text{max})}$	0.333 4.44	W mW/°C
Collector Current — Continuous	I_C	-70	mA
Maximum Junction Temperature	$T_{J\text{max}}$	150	°C
Storage Temperature All	T_{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Ratings	Symbol	Value	Unit
Thermal Resistance, Junction to Case (MMBR521LT1, MRF5211LT1)	$R_{\theta JC}$	225	°C/W

DEVICE MARKING

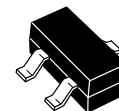
MMBR521LT1 = 7M	MRF5211LT1 = 04
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NOTE:

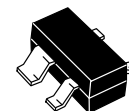
1. Case Temperature is measured on the collector lead closest to the package. For case temperatures above $+75^\circ\text{C}$: $P_{\text{DISP}(\text{max})} = (T_{J\text{max}} - T_C) / R_{\theta JC}$

MMBR521LT1
MRF5211LT1

$I_C = -70 \text{ mA}$
HIGH-FREQUENCY
TRANSISTOR
PNP SILICON



CASE 318-08, STYLE 6
SOT-23
LOW PROFILE
(TO-236AA/AB)
MMBR521LT1



CASE 318A-05, STYLE 1
SOT-143
LOW PROFILE
MRF5211LT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ($I_C = -1.0\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	-10	-12	—	Vdc
Collector–Base Breakdown Voltage ($I_C = -0.1\text{ mA}$, $I_E = 0$)	$V_{(BR)CBO}$	-20	—	—	Vdc
Emitter–Base Breakdown Voltage ($I_E = -50\text{ }\mu\text{A}$, $I_C = 0$)	$V_{(BR)EBO}$	-2.5	—	—	Vdc
Collector Cutoff Current ($V_{CB} = -8.0\text{ Vdc}$, $I_E = 0$)	I_{CBO}	—	—	-10	μA
ON CHARACTERISTICS					
DC Current Gain ($I_C = -30\text{ mA}$, $V_{CE} = -5.0\text{ Vdc}$)	h_{FE}	25	—	125	—
DYNAMIC CHARACTERISTICS					
Collector–Base Capacitance ($V_{CB} = -6.0\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{cb}	—	1.0	1.5	pF
Current Gain — Bandwidth Product ($V_{CE} = -8.0\text{ V}$, $I_C = -35\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = -8.0\text{ V}$, $I_C = -50\text{ mA}$, $f = 1.0\text{ GHz}$)	f_T	—	3.4 4.2	—	GHz
	MMBR521LT1 MRF5211LT1	—		—	
FUNCTIONAL TESTS					
Power Gain at Minimum Noise Figure ($V_{CE} = -6.0\text{ V}$, $I_C = -5.0\text{ mA}$, $f = 500\text{ MHz}$) ($V_{CE} = -6.0\text{ V}$, $I_C = -5.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = -6.0\text{ V}$, $I_C = -5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	G_{NFmin}	13 8.0 10	15 10 11	—	dB
	MMBR521LT1 MMBR521LT1 MRF5211LT1				
Noise Figure — Minimum ($V_{CE} = -6.0\text{ V}$, $I_C = -5.0\text{ mA}$, $f = 500\text{ MHz}$) ($V_{CE} = -6.0\text{ V}$, $I_C = -5.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = -6.0\text{ V}$, $I_C = -5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	NF_{min}	—	1.5 2.5 2.8	2.5 3.5 3.5	dB
	MMBR521LT1 MMBR521LT1 MRF5211LT1				

TYPICAL CHARACTERISTICS

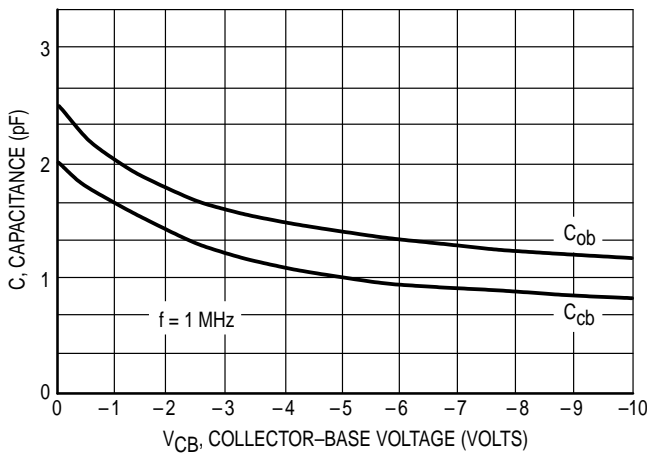


Figure 1. Junction Capacitance versus Voltage

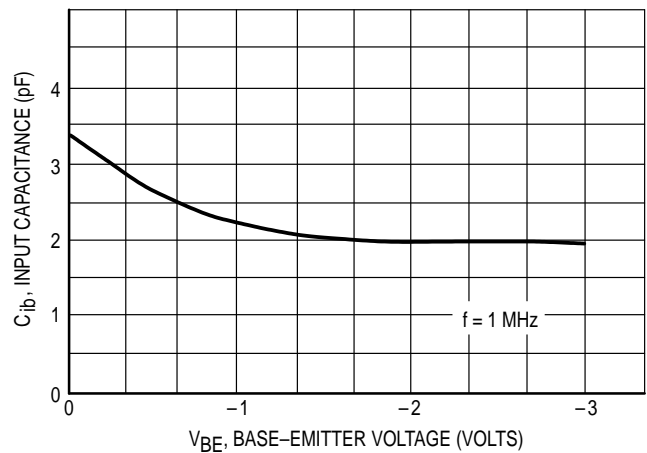


Figure 2. Input Capacitance versus Voltage

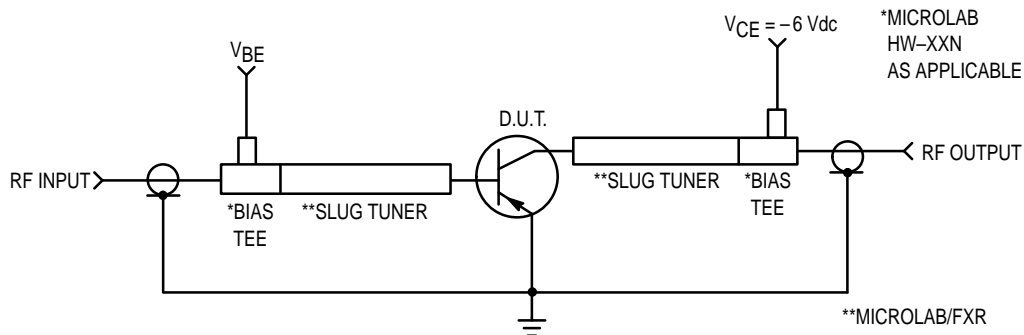


Figure 3. Functional Circuit Schematic

**TYPICAL CHARACTERISTICS
MMBR521LT1**

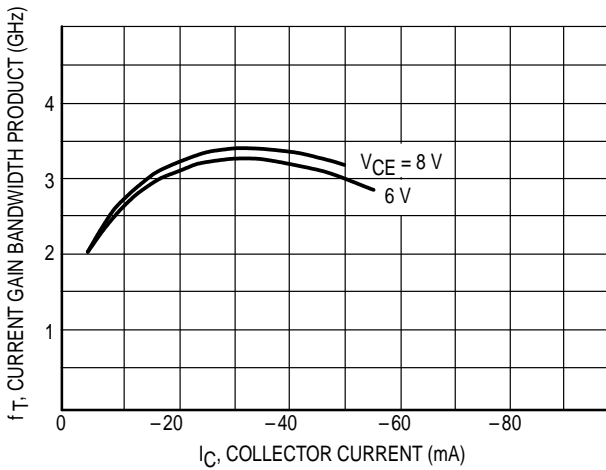


Figure 4. Current Gain Bandwidth Product versus Collector Current

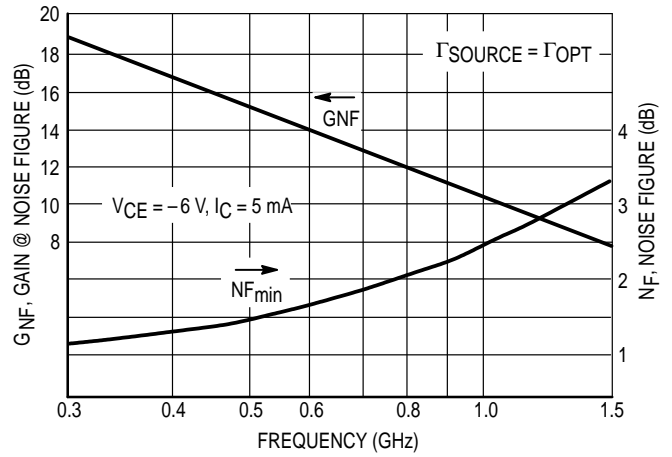


Figure 5. Minimum Noise Figure & Gain @ Noise Figure versus Frequency

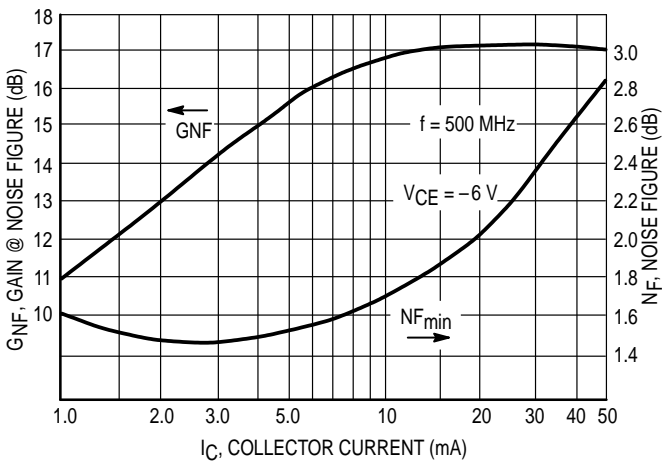


Figure 6. Minimum Noise Figure & Gain @ Noise Figure versus Collector Current

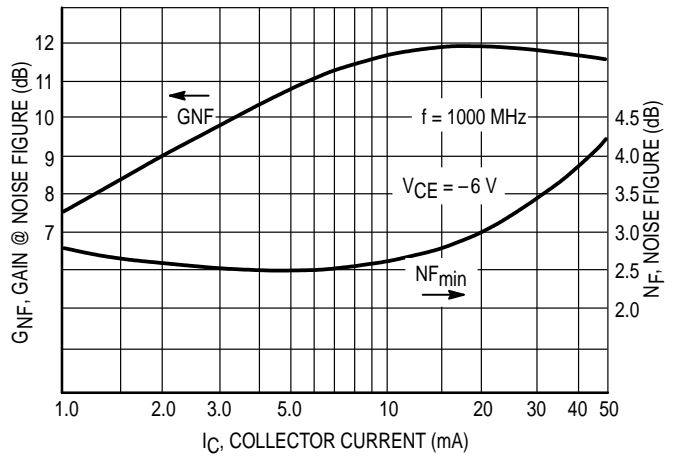


Figure 7. Minimum Noise Figure & Gain @ Noise Figure versus Collector Current

TYPICAL CHARACTERISTICS MRF5211LT1

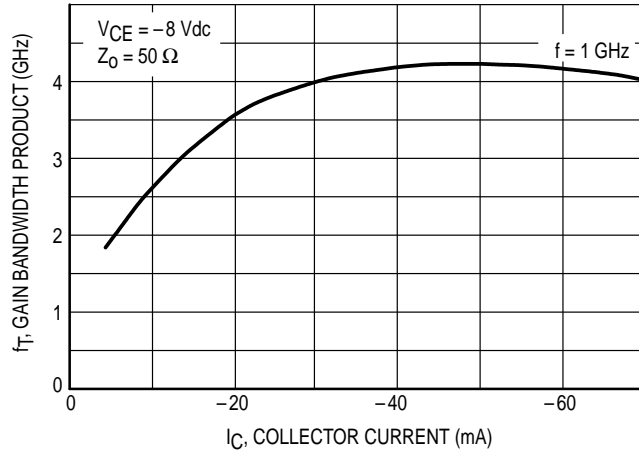


Figure 8. Gain–Bandwidth Product versus Current

GAIN AND NOISE FIGURE versus FREQUENCY

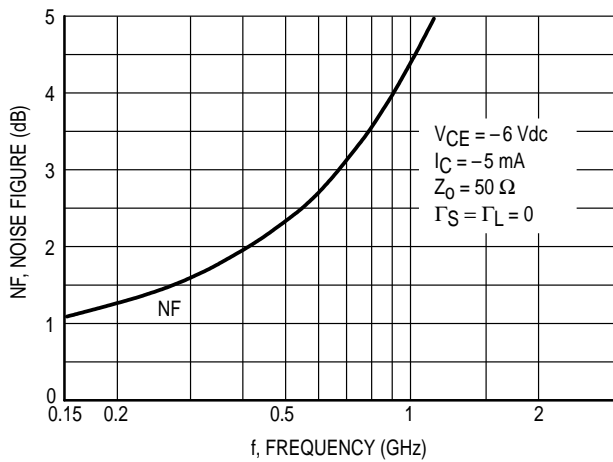


Figure 9. 50 Ohm Noise Figure

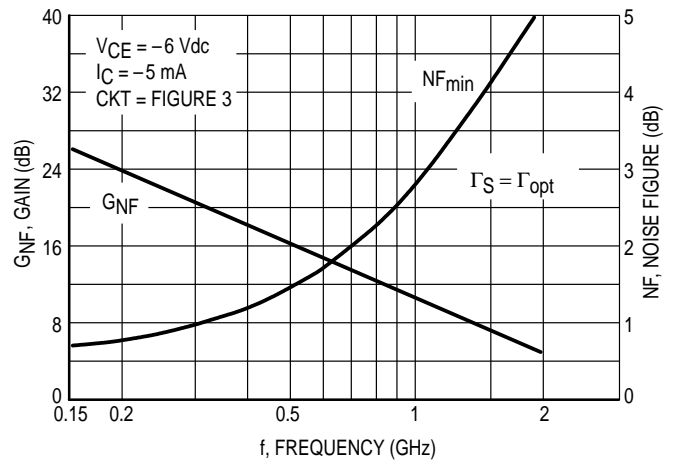


Figure 10. Tuned Circuit

GAIN AND NOISE FIGURE versus CURRENT

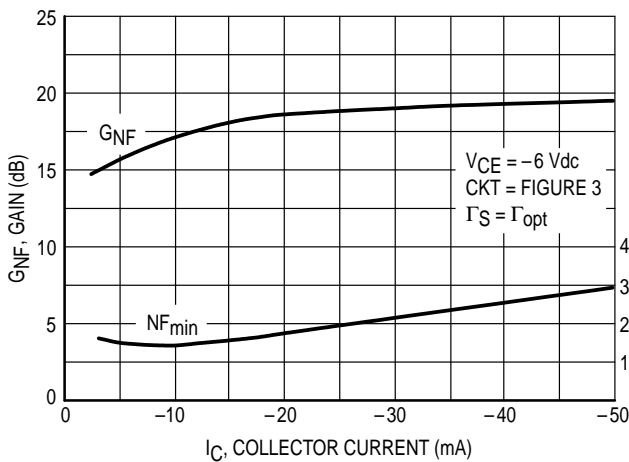


Figure 11. Tuned Circuit — Frequency 500 MHz

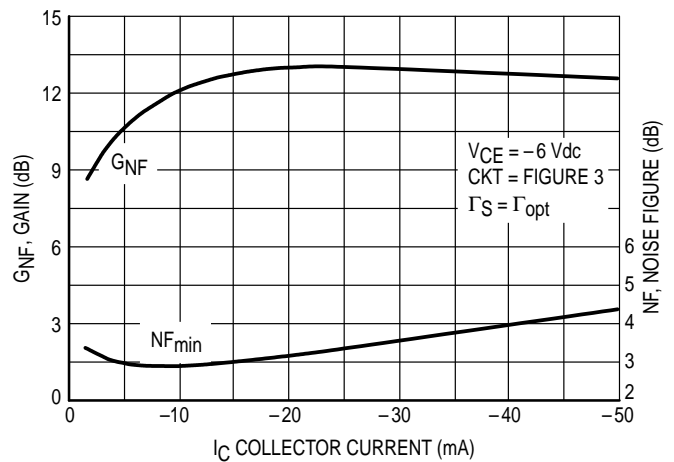


Figure 12. Tuned Circuit — Frequency 1.0 GHz

TYPICAL CHARACTERISTICS — continued
MRF5211LT1

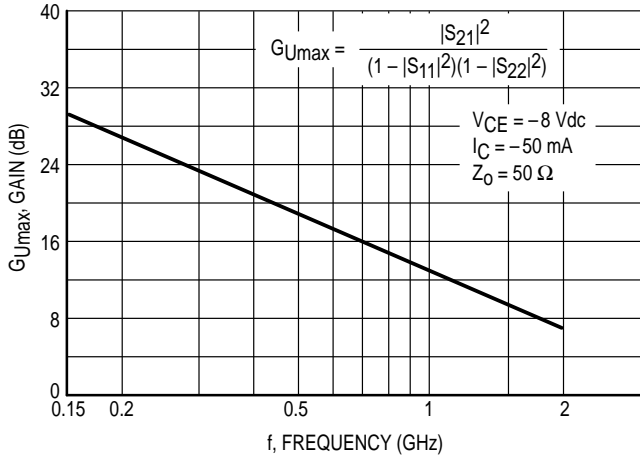


Figure 13. G_{Umax} versus Current

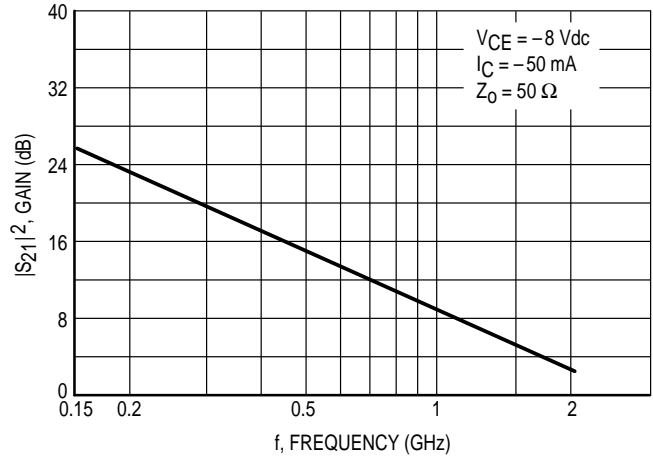


Figure 14. Insertion Gain versus Frequency

V _{CE} (Vdc)	I _C (mA)	f (MHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂		
			S ₁₁	∠φ	S ₂₁	∠φ	S ₁₂	∠φ	S ₂₂	∠φ	
6	5	100	0.754	-67	11.453	141	0.040	59	0.818	-24	
		300	0.683	-132	6.106	105	0.065	39	0.549	-37	
		500	0.667	-157	3.954	89	0.071	39	0.472	-40	
		700	0.660	-171	2.890	78	0.078	44	0.452	-44	
		900	0.656	179	2.294	69	0.085	50	0.449	-49	
		1000	0.654	175	2.086	65	0.091	53	0.451	-52	
		1500	0.641	158	1.442	48	0.130	64	0.480	-66	
		2000	0.672	140	1.108	36	0.188	69	0.466	-79	
		2500	0.681	124	0.917	26	0.261	66	0.483	-94	
		3000	0.681	110	0.793	18	0.343	60	0.493	-110	
	3500	0.686	96	0.716	13	0.426	52	0.500	-126		
	4000	0.683	84	0.674	9	0.503	43	0.502	-143		
	4500	0.678	73	0.653	6	0.568	34	0.503	-160		
	5000	0.669	64	0.653	3	0.620	24	0.507	-176		
	10	10	100	0.632	-92	16.621	131	0.032	55	0.694	-33
			300	0.618	-149	7.460	98	0.050	47	0.417	-41
			500	0.618	-168	4.671	85	0.061	53	0.358	-44
			700	0.616	-178	3.392	76	0.076	58	0.346	-47
			900	0.615	173	2.672	68	0.092	62	0.347	-52
			1000	0.613	170	2.429	64	0.100	63	0.352	-55
			1500	0.601	155	1.677	48	0.150	66	0.382	-68
			2000	0.633	138	1.294	36	0.208	66	0.371	-80
			2500	0.642	124	1.078	25	0.273	62	0.391	-94
			3000	0.646	110	0.929	16	0.346	56	0.408	-109
	3500	0.656	98	0.827	10	0.422	49	0.421	-124		
	4000	0.662	86	0.756	4	0.494	41	0.431	-141		
	4500	0.664	75	0.709	1	0.554	32	0.442	-158		
	5000	0.664	66	0.683	-3	0.609	24	0.455	-174		
	50	50	100	0.547	-149	21.107	115	0.017	63	0.441	-43
			300	0.606	-174	7.891	90	0.037	68	0.260	-42
500			0.616	177	4.811	80	0.058	73	0.239	-44	
700			0.616	171	3.480	72	0.080	73	0.242	-48	
900			0.616	165	2.746	65	0.102	73	0.248	-54	
1000			0.615	163	2.479	61	0.113	72	0.255	-57	
1500			0.606	150	1.717	46	0.169	69	0.293	-71	
2000			0.643	135	1.327	33	0.229	65	0.289	-82	
2500			0.654	122	1.097	22	0.292	60	0.315	-96	
3000			0.662	108	0.940	13	0.359	54	0.337	-110	
3500	0.672	96	0.825	6	0.427	47	0.356	-126			
4000	0.680	84	0.743	1	0.493	39	0.373	-142			
4500	0.682	74	0.688	-2	0.551	31	0.391	-159			
5000	0.679	64	0.658	-5	0.601	22	0.409	-175			
10	5	100	0.792	-59	11.498	144	0.036	62	0.848	-21	
		300	0.681	-123	6.513	108	0.061	41	0.598	-32	
		500	0.652	-150	4.278	91	0.068	40	0.518	-36	
		700	0.639	-166	3.142	80	0.073	44	0.496	-39	
		900	0.631	-177	2.491	71	0.081	49	0.489	-44	
		1000	0.628	179	2.264	67	0.086	53	0.492	-46	
		1500	0.616	161	1.560	50	0.120	64	0.514	-58	
		2000	0.644	142	1.199	37	0.171	69	0.500	-70	
		2500	0.654	126	0.985	26	0.238	68	0.516	-83	
		3000	0.661	111	0.843	18	0.314	63	0.523	-98	
3500	0.670	98	0.749	12	0.399	56	0.529	-113			
4000	0.672	85	0.690	8	0.479	47	0.528	-129			
4500	0.671	73	0.656	5	0.549	38	0.524	-146			
5000	0.665	63	0.649	3	0.609	28	0.523	-162			
10	10	100	0.666	-80	17.255	135	0.030	58	0.738	-28	
		300	0.596	-141	8.143	101	0.047	48	0.465	-37	
		500	0.587	-162	5.139	87	0.059	53	0.404	-38	
		700	0.581	-174	3.741	78	0.072	58	0.388	-41	
		900	0.578	177	2.947	70	0.086	61	0.387	-45	
		1000	0.577	174	2.670	66	0.095	63	0.389	-48	
		1500	0.565	158	1.856	50	0.139	66	0.413	-60	
		2000	0.596	140	1.431	38	0.191	66	0.402	-70	
		2500	0.608	126	1.177	26	0.253	64	0.420	-82	
		3000	0.619	112	1.008	17	0.319	59	0.434	-96	
3500	0.632	99	0.886	9	0.393	52	0.444	-110			
4000	0.644	87	0.797	3	0.465	44	0.453	-126			
4500	0.652	75	0.732	-1	0.532	36	0.457	-143			
5000	0.654	65	0.694	-4	0.589	28	0.465	-159			

Table 1. MMBR521LT1 Common Emitter S-Parameters

V _{CE} (Vdc)	I _C (mA)	f (MHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
			S ₁₁	∠φ	S ₂₁	∠φ	S ₁₂	∠φ	S ₂₂	∠φ
-6.0	-5.0	200	0.82	-114	7.9	118	0.07	35	0.59	-46
		500	0.81	-158	4.0	88	0.08	21	0.40	-54
		1000	0.79	175	2.0	67	0.08	21	0.37	-68
		1500	0.76	158	1.3	50	0.07	30	0.43	-82
		2000	0.74	143	1.0	38	0.08	47	0.47	-95
	-10	200	0.78	-137	10.6	109	0.05	32	0.43	-63
		500	0.79	-168	4.9	84	0.06	28	0.26	-75
		1000	0.77	169	2.5	66	0.06	39	0.24	-87
		1500	0.74	155	1.6	50	0.08	49	0.29	-97
		2000	0.71	140	1.2	39	0.10	55	0.32	-106
	-50	200	0.77	-167	13.1	99	0.02	45	0.26	-108
		500	0.77	176	5.7	80	0.04	57	0.18	-132
		1000	0.76	161	2.8	65	0.06	65	0.17	-142
		1500	0.73	149	1.9	51	0.08	67	0.19	-137
		2000	0.70	136	1.4	40	0.12	65	0.20	-137
-8.0	-5.0	200	0.82	-109	8.1	119	0.07	36	0.62	-43
		500	0.80	-154	4.2	90	0.08	22	0.42	-52
		1000	0.78	175	2.2	67	0.08	22	0.38	-65
		1500	0.75	159	1.4	50	0.07	31	0.43	-78
		2000	0.72	143	1.0	37	0.09	43	0.46	-89
	-10	200	0.77	-132	11.2	110	0.05	33	0.45	-61
		500	0.77	-167	5.2	86	0.06	29	0.27	-70
		1000	0.76	169	2.6	67	0.06	39	0.25	-81
		1500	0.73	155	1.7	51	0.07	49	0.29	-90
		2000	0.70	140	1.3	39	0.10	54	0.31	-98
	-50	200	0.75	-164	14.2	100	0.02	43	0.26	-101
		500	0.76	178	6.1	82	0.04	55	0.17	-121
		1000	0.75	163	3.1	67	0.06	64	0.15	-131
		1500	0.72	151	2.0	53	0.08	67	0.18	-126
		2000	0.70	139	1.5	42	0.11	68	0.19	-127

Table 2. MRF5211LT1 Common Emitter S-Parameters

PACKAGE DIMENSIONS

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE 6:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

CASE 318-08 ISSUE AE

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.80	3.04	0.110	0.120
B	1.20	1.39	0.047	0.055
C	0.84	1.14	0.033	0.045
D	0.39	0.50	0.015	0.020
F	0.79	0.93	0.031	0.037
G	1.78	2.03	0.070	0.080
H	0.013	0.10	0.0005	0.004
J	0.08	0.15	0.003	0.006
K	0.46	0.60	0.018	0.024
L	0.445	0.60	0.0175	0.024
R	0.72	0.83	0.028	0.033
S	2.11	2.48	0.083	0.098

STYLE 1:
PIN 1. COLLECTOR
2. EMITTER
3. EMITTER
4. BASE

CASE 318A-05 ISSUE J

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